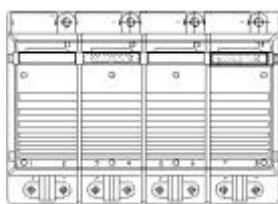


# SKiiP 432GH120-4D



**SKiiP® 2**

## 4-pack - integrated intelligent Power System

### Power section

#### SKiiP 432GH120-4D

### Features

- SKiiP technology inside
- CAL diode technology
- Integrated current sensor
- Integrated temperature sensor
- Integrated heat sink
- IEC 60721-3-3 (humidity) class 3K3/IE32 (SKiiP® 2 System)
- IEC 60068-1 (climate) 40/125/56
- UL recognized file no. E63532

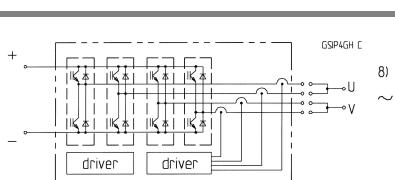
1) with assembly of suitable MKP capacitor per terminal (SEMIKRON type is recommended)

8) AC connection busbars must be connected by the user; copper busbars available on request

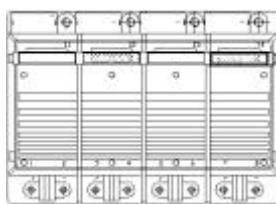
Absolute Maximum Ratings		$T_s = 25^\circ\text{C}$ unless otherwise specified	
Symbol	Conditions	Values	Units
<b>IGBT</b>			
$V_{CES}$		1200	V
$V_{CC}^1)$	Operating DC link voltage	900	V
$V_{GES}$		$\pm 20$	V
$I_C$	$T_s = 25 \text{ (70)}^\circ\text{C}$	400 (300)	A
<b>Inverse diode</b>			
$I_F = -I_C$	$T_s = 25 \text{ (70)}^\circ\text{C}$	400 (300)	A
$I_{FSM}$	$T_j = 150^\circ\text{C}$ , $t_p = 10 \text{ ms}$ ; sin.	2880	A
$I^2t$ (Diode)	Diode, $T_j = 150^\circ\text{C}$ , 10 ms	41	kA <sup>2</sup> s
$T_j$ ( $T_{stg}$ )		- 40 (- 25) ... + 150 (125)	°C
$V_{isol}$	AC, 1 min. (mainterminals to heat sink)	3000	V

Characteristics		$T_s = 25^\circ\text{C}$ unless otherwise specified		
Symbol	Conditions	min.	typ.	max.
<b>IGBT</b>				
$V_{CEsat}$	$I_C = 350 \text{ A}$ , $T_j = 25 \text{ (125)}^\circ\text{C}$	2,6 (3,1)	3,1	V
$V_{CEO}$	$T_j = 25 \text{ (125)}^\circ\text{C}$	1,2 (1,3)	1,5 (1,6)	V
$r_{CE}$	$T_j = 25 \text{ (125)}^\circ\text{C}$	3,8 (5)	4,5 (5,8)	mΩ
$I_{CES}$	$V_{GE} = 0 \text{ V}$ , $V_{CE} = V_{CES}$ , $T_j = 25 \text{ (125)}^\circ\text{C}$	(20)	0,8	mA
$E_{on} + E_{off}$	$I_C = 350 \text{ A}$ , $V_{CC} = 600 \text{ V}$ $T_j = 125^\circ\text{C}$ , $V_{CC} = 900 \text{ V}$		105	mJ
			185	mJ
$R_{CC' + EE'}$	terminal chip, $T_j = 125^\circ\text{C}$	0,25		mΩ
$L_{CE}$	top, bottom	7,5		nH
$C_{CHC}$	per phase, AC-side	2,8		nF
<b>Inverse diode</b>				
$V_F = V_{EC}$	$I_F = 300 \text{ A}$ , $T_j = 25 \text{ (125)}^\circ\text{C}$	2,1 (1,9)	2,6	V
$V_{TO}$	$T_j = 25 \text{ (125)}^\circ\text{C}$	1,3 (1)	1,4 (1,1)	V
$r_T$	$T_j = 25 \text{ (125)}^\circ\text{C}$	2,5 (3)	3,4 (3,9)	mΩ
$E_{rr}$	$I_C = 350 \text{ A}$ , $V_{CC} = 600 \text{ V}$ $T_j = 125^\circ\text{C}$ , $V_{CC} = 900 \text{ V}$		12	mJ
			15	mJ
<b>Mechanical data</b>				
$M_{dc}$	DC terminals, SI Units	6	8	Nm
$M_{ac}$	AC terminals, SI Units	13	15	Nm
w	SKiiP® 2 System w/o heat sink		3,5	kg
w	heat sink		8,5	kg
<b>Thermal characteristics (P16 heat sink; 275m<sup>3</sup>/h); "r" reference to temperature sensor</b>				
$R_{th(j-s)I}$	per IGBT		0,064	K/W
$R_{th(j-s)D}$	per diode		0,188	K/W
$R_{th(s-a)}$	per module		0,033	K/W
$Z_{th}$	$R_i$ (mK/W) (max. values)		$\tau_{ai}(s)$	
	1      2      3      4	1      2      3      4		
$Z_{th(j-r)I}$	7      50     8      0	1      0,13    0,001    1		
$Z_{th(j-r)D}$	21     144    23     0	1      0,13    0,001    1		
$Z_{th(r-a)}$	1,6    22     7      2,4	494    165    20     0,03		

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Case S 5



**SKiiP® 2**

## 4-pack - integrated intelligent Power System

### 4-pack integrated gate driver

### SKiiP 432GH120-4D

#### Gate driver features

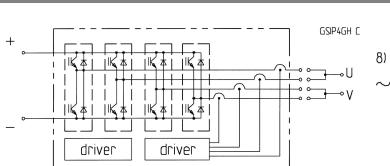
- Two separate and independent "GB"-type driver
- CMOS compatible inputs
- Wide range power supply
- Integrated circuitry to sense phase current, heat sink temperature and DC-bus voltage (option)
- U-option is integrated on left driver, (DC terminals at bottom; refer to case drawing)
- Short circuit protection
- Over current protection
- Over voltage protection (option)
- Power supply protected against under voltage
- Interlock of top/bottom switch
- Isolation by transformer
- Fibre optic interface (option)
- IEC 60068-1 (climate) 25/85/56

Absolute Maximum Ratings		$T_a = 25^\circ\text{C}$ unless otherwise specified		
Symbol	Conditions	Values		Units
$V_{S1}$	stabilized 15 V power supply	18		V
$V_{S2}$	unstabilized 24 V power supply	30		V
$V_{iH}$	input signal voltage (high)	15 + 0,3		V
$\frac{dv}{dt}$	secondary to primary side	75		$\text{kV}/\mu\text{s}$
$V_{isolIO}$	input / output (AC, r.m.s., 2s)	3000		Vac
$V_{isol12}$	output 1 / output 2 (AC, r.m.s., 2s)	1500		Vac
$f_{sw}$	switching frequency	20		kHz
$f_{out}$	output frequency for $I=I_C \sin.$	1		kHz
$T_{op} (T_{stg})$	operating / storage temperature	- 40 ... + 85		°C

Characteristics ( $T_a = 25^\circ\text{C}$ )				
Symbol	Conditions	min.	typ.	max.
$V_{S1}$	supply voltage stabilized	14,4	15	15,6
$V_{S2}$	supply voltage non stabilized	20	24	30
$I_{S1}$	$V_{S1} = 15 \text{ V}$	$210+320*f/f_{\text{max}}+1,3*(I_{AC}/A)$		
$I_{S2}$	$V_{S2} = 24 \text{ V}$	$160+220*f/f_{\text{max}}+1,0*(I_{AC}/A)$		
$V_{iT+}$	input threshold voltage (High)	12,3		
$V_{iT-}$	input threshold voltage (Low)	4,6		
$R_{IN}$	input resistance	10		
$t_{d(on)}IO$	input-output turn-on propagation time	1,5		
$t_{d(off)}IO$	input-output turn-off propagation time	1,4		
$t_{pERRRESET}$	error memory reset time	9		
$t_{TD}$	top / bottom switch : interlock time	3,3		
$I_{analogOUT}$	8 V corresponds to max. current of 15 V supply voltage (available when supplied with 24 V)	400		
$I_{Vs1outmax}$	output current at pin 12/14	50		
$I_{AOmax}$	logic low output voltage	5		
$V_{O1}$	logic high output voltage	0,6		
$V_{OH}$		30		
$I_{TRIPSC}$	over current trip level ( $I_{analog OUT} = 10 \text{ V}$ )	500		
$I_{TRIPLG}$	ground fault protection	A		
$T_{tp}$	over temperature protection	110		
$U_{DCTRIP}$	trip level of $U_{DC}$ -protection ( $U_{analog OUT} = 9 \text{ V}$ ); (option)	900		
		120		
		V		

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**Case S 5**